



Lampiran- lampiran

Lampiran 1. Data sheet IC TL431,BC547,BC557

- IC TL431



TL431A Adjustable Precision Shunt Regulator

FEATURES

- Programmable Output Voltage to 40V
- Low Dynamic Output Impedance 0.2Ω
- Sink Current Capability of 0.1 mA to 100 mA
- Equivalent Full-Range Temperature Coefficient of 50 ppm/°C
- Temperature Compensated for Operation over Full Rated Operating Temperature Range
- Low Output Noise Voltage
- Fast Turn on Response
- TO-92 or SOT-23 and SOT-89, SO8 packages

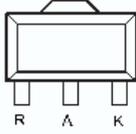
PIN CONNECTIONS



TO-92
TL431ACL_P-Bulk Pack
TL431ACL_{PM}- Ammo Pack



SOT-89
TL431ACPK



SOT-23
TL431ALT1

SO8
TL431ACMX

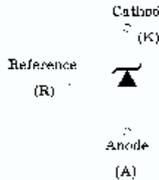
CATHODE	1	REF
ANODE	2	ANODE
ANODE	3	ANODE
NC	4	NC



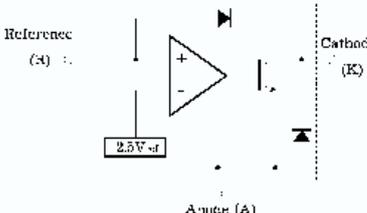
DESCRIPTION

The TL431A is a three-terminal adjustable regulator series with a guaranteed thermal stability over appl cable temperature ranges. The output voltage may be set to any value between Vref (approximately 2.5 volts) and 36 volts with two external resistors. These devices have a typical dynamic output impedance of 0.2Ω. Active output circuitry provides a very sharp turn-on characteristic, making these devices excellent replacement for zener diodes in many applications. The TL431A is characterized for operation from -0°C to +70°C.

SYMBOL



FUNCTIONAL BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATINGS

(Operating temperature range applies unless otherwise specified)

Characteristic	Symbol	Value	Unit
Cathode Voltage	V _{KA}	40	V
Cathode Current Range (Continuous)	I _K	100 ~ 150	mA
Reference Input Current Range	I _{REF}	0.05 ~ 10	mA
Power Dissipation at 25°C:	P _D		
TO-92 Package (R _{JA} = 178°C/W)		0.7	W
SOT-23-3 Package (R _{JA} = 625°C/W)		0.2	W
Junction Temperature Range	T _J	0 ~ 150	°C
Operating Temperature Range	T _R	0 ~ 70	°C
Storage Temperature Range	T _{stg}	-65 ~ +150	°C

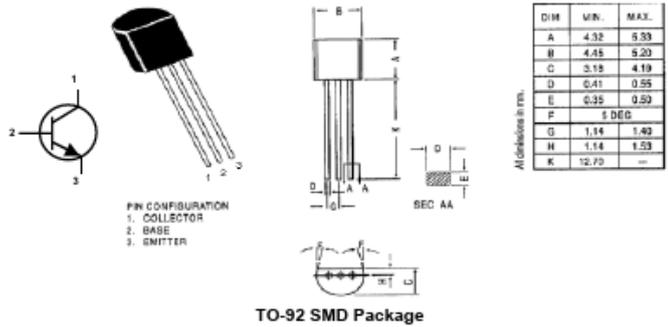
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- Transistor BC 547



BC546
BC547
BC548

NPN Silicon Planar Epitaxial Transistors



Absolute Maximum Ratings ($T_a = 25\text{ }^\circ\text{C}$ unless specified otherwise)

DESCRIPTION	SYMBOL	BC546	BC547	BC548	UNITS
Collector Base Voltage	V_{CBO}	80	50	30	V
Collector Emmitter Voltage ($V_{BE} = 0V$)	V_{CES}	80	50	30	V
Collector Emitter Voltage	V_{CEO}	65	45	30	V
Emitter Base Voltage	V_{EBO}	6	6	5	V
Collector Current (DC)	I_C		100		mA
Collector Current - Peak	I_{CM}		200		mA
Emitter Current - Peak	I_{EM}		200		mA
Base Current - Peak	I_{BM}		200		mA
Total power dissipation up to $T_{amb} = 25\text{ }^\circ\text{C}$	P_{tot}		500		mW
Storage Temperature	T_{stg}		-55 to +150		$^\circ\text{C}$
Junction Temperature	T_J		150		$^\circ\text{C}$
<i>Thermal Resistance</i>					
From junction to ambient	$R_{\theta(j-a)}$		250		$^\circ\text{C/W}$



- Transistor BC557



Continental Device India Limited
An ISO/TS 16949, ISO 9001 and ISO 14001 Certified Company



PNP SILICON PLANAR EPITAXIAL TRANSISTORS



**BC556, A, B,
BC557, A, B, C
BC558, A, B, C**

**TO-92
Plastic Package**
For Lead Free Parts, Device
Part # will be Prefixed with
"T"

Amplifier Transistors

ABSOLUTE MAXIMUM RATINGS (T_a=25°C)

DESCRIPTION	SYMBOL	BC556	BC557	BC558	UNITS
Collector Emitter Voltage	V _{CEO}	65	45	30	V
Collector Emitter Voltage	V _{CES}	80	50	30	V
Collector Base Voltage	V _{CBO}	80	50	30	V
Emitter Base Voltage	V _{EBO}	5			V
Collector Current Continuous	I _C	100			mA
Collector Current Peak	I _{CM}	200			mA
Base Current Peak	I _{BM}	200			mA
Emitter Current Peak	I _{EM}	200			mA
Power Dissipation at T _a =25°C	P _D	500			mW
Derate Above 25°C		4.0			mW/°C
Storage Temperature	T _{stg}	- 65 to +150			°C
Junction Temperature	T _J	150			°C

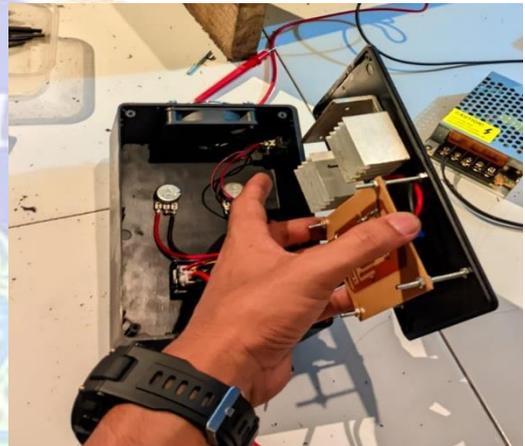
THERMAL RESISTANCE

Junction to Ambient in free air	R _{th(j-a)}	250	°C/W
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ELECTRICAL CHARACTERISTICS (T_a=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	BC556	BC557	BC558	UNITS
Collector Emitter Voltage	V _{CEO}	I _C =2mA, I _B =0	>65	>45	>30	V
Collector Base Voltage	V _{CBO}	I _C =100μA, I _E =0	>80	>50	>30	V
Emitter Base Voltage	V _{EBO}	I _E =100μA, I _C =0	>5.0			V
Collector Cut Off Current	I _{CBO}	V _{CB} =30V, I _E =0 ALL V _{CB} =30V, I _E =0, T _J =150°C ALL	<15			nA μA
Collector Cut Off Current	I _{CES}	V _{CE} =80V, V _{BE} =0 V _{CE} =50V, V _{BE} =0 V _{CE} =30V, V _{BE} =0 V _{CE} =80V, V _{EB} =0, T _J =125°C V _{CE} =50V, V _{EB} =0, T _J =125°C V _{CE} =30V, V _{EB} =0, T _J =125°C	<15 <4.0	<15 <4.0	<15 <4.0	nA nA nA μA μA μA

Lampiran 2. Dokumentasi Pembuatan Alat



RIWAYAT HIDUP



Ketut Budi Arimbawa lahir di Jinengdalem pada tanggal 20 Juni 2002. Penulis lahir dari pasangan suami istri Bapak Wayan Somayasa dan Ibu Komang Sukemi. Penulis berkebangsaan Indonesia dan beragama Hindu. Kini penulis bertempat di Desa Jinengdalem Banjar Dinas Gambang, Kecamatan Buleleng, Kabupaten Buleleng, Provinsi Bali. Penulis menyelesaikan pendidikan dasar di SD Negeri 2 Jinengdalem dan lulus pada tahun 2015. Kemudian penulis melanjutkan di SMP Negeri 5 Singaraja dan lulus pada tahun 2018. Pada tahun 2021, penulis lulus dari SMK Negeri 3 Singaraja jurusan Teknik Audio Video dan melanjutkan ke Diploma IV Jurusan Teknologi Industri Program Studi Teknologi Rekayasa Sistem Elektronika di Universitas Pendidikan Ganesha. Pada semester akhir tahun 2024 penulis telah menyelesaikan Tugas Akhir yang berjudul “Rancang Bangun *Solar Charger Controller Dengan Series Regulator* Untuk Sistem Penggerak Motor Listrik Perahu Nelayan”. Selanjutnya, mulai tahun 2024 sampai dengan penulisan menulis skripsi ini, penulis masih terdaftar sebagai mahasiswa Program Studi Diploma IV Teknologi Rekayasa Sistem Elektronika di Universitas Pendidikan Ganesha.

